Seat No.

### M.Sc. (Part – I) (Semester – I) Examination, 2015 (CBCS) (New)

#### **PHYSICS (Material Science)**

Paper No. - I: Mathematical Techniques

Day and Date: Monday, 16-11-2015 Max. Marks: 70

Time: 10.30 a.m. to 1.00 p.m.

Instructions: 1) Q. No. 1 and Q. No. 2 are compulsory.

- 2) Answer any three from Q. No. 3 to Q. No. 7.
- 3) Use of Non programable calculator is allowed.
- 4) All questions carry equal marks.

1. 1) Choose the correct alternative:

- i) The value of  $(\cos(\pi/3) + i \sin(\pi/3)^{1/3} =$ 
  - a) 1
- b) 0
- c) i
- d) i

ii) The Cauchy Riemann Equations are given by

a)  $u_x = v_v, v_x = -u_v$ 

b)  $u_{xx} + u_{yy} = 0$ ,  $v_{xx} + v_{yy} = 0$ 

c)  $-u_{x} = v_{y}, v_{x} = u_{y}$ 

d)  $u_{xx} - u_{yy} = 0$ ,  $v_{xx} - v_{yy} = 0$ 

iii) The particular integral of the ordinary Differential Equation (DE) is

- a) General solution of DE
- b) General solution of associate DE
- c) Solution of Associate DE
- d) Solution of ODE

iv) The Particular Integral of  $(D^2 - 4)y = e^x$  is

a)  $\frac{X}{6}e^{x}$ 

b)  $\frac{X^{2}}{6}e^{x}$ 

c)  $\frac{1}{3}e^{x}$ 

d) 0



- v) Inverse Laplace Transform of  $\frac{s-2}{(s-2)^2+1}$  =
  - a) e<sup>2t</sup> cos t
- b) e<sup>t</sup> cost
- c) e<sup>2t</sup> sin t
- d) e<sup>t</sup> sin t
- vi) Fourier Sine Integral of f(s) is given by

  - a)  $\frac{2}{\pi} \int_{0}^{\pi} \sin wx \int_{0}^{\pi} f(s) \sin ws. dxds$  b)  $\frac{2}{\pi} \int_{0}^{\pi} \sin wx \int_{0}^{\pi} f(s) \cos ws. dxds$
  - c)  $\frac{2}{\pi} \int_{0}^{\pi} \sin w x \int_{0}^{\pi} f(s) \sin w s$ . dwds dy  $\frac{2}{\pi} \int_{0}^{\pi} \sin w x \int_{0}^{\pi} f(s) \cos w s$ . dwds

- 2) State **true** or **false**:

  - i) The value of f'(z) for f(z) = u + iv is  $u_x + iv_y$ .
  - ii) If the vectors are Linearly dependent then one vector can be expressed as quadratic combination of others.
  - iii) Matrix digitalization of symmetric matrix is possible only if it has non-zero eigen values.
  - iv) Laplace Transform is possible only if t > 0.
  - v)  $\frac{1}{D^2 16}$  cos 4x is equal to  $\frac{1}{-32}$  cos 4x.
  - vi) The conditions for expansion of function in a Fourier series are known as Eulers conditions.
  - vii) The value of  $\frac{(\cos\theta+i\sin\theta)^8}{(\sin\theta+i\cos\theta)^4}$  is cos 12  $\theta$  i sin 12  $\theta$ .
  - viii) L{e<sup>-t</sup> sin 3t} =  $\frac{3}{(s+1)^2+9}$ .
- 2. Write short notes on:
  - 1) Write a note on Harmonic conjugates of an Analytic Function.

4

- 2) Write a note on the principle of superposition of the homogeneous differential equation.
  - 5
- 3) Write a note on Half Range Sine Fourier Series of f(x) on General Interval.



- 3. 1) Find Inverse Laplace Transform of  $\frac{s^2}{(s^2+9)(s^2+1)}$ .
  - 2) Consider all the non zero solutions of the equation y'' + 12y' + 36y = 0, determine their behaviour as  $t \to \infty$ .
- 4. 1) Show that  $u = \frac{1}{2} \log(x^2 + y^2)$  is harmonic and find its harmonic conjugate. 10
  - 2) Find Laplace Transform of  $\frac{1-e^{2t}}{t}$ .
- 5. 1) Define Adjoint of the matrix. Hence find A<sup>-1</sup> of the matrix using adjoint matrix
  - method for  $\begin{pmatrix} 2 & 3 & 4 \\ 3 & -8 & 5 \\ 4 & 5 & -9 \end{pmatrix}$ .
  - 2) Solve y'' 6y' + 25y = 0 at y(0) = 2, y'(0) = 1 and find the limit, as  $t \to \infty$ , of the solution.
- 6. 1) Find Fourier sine transform of  $f(x) = \frac{e^{-ax}}{x}$ .
  - 2) Evaluate the integral using Laplace transform method  $\int_{0}^{\infty} \frac{e^{-t} \sin t}{t} dt$ .
- 7. 1) Find Laplace of  $\frac{d}{dt} t \sin 2t$ .
  - 2) Find Fourier Series of  $f(x) = \left(\frac{a}{2} X\right)$  in (0, a).

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# M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Materials Science) (Paper – II) (New) (CBCS) Condensed Matter Physics

Day and Date: Wednesday, 18-11-2015	Total Marks : 70
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Time: 10.30 a.m. to 1.00 p.m.

1.

**Instructions**: 1) Attempt **five** questions.

- 2) Q. (1) and Q. (2) are compulsory.
- 3) Attempt any three from Q. 3 to Q. 7.

	4) Figures to the <b>ri</b> g	ght indicate full marks. ntific calculator is allowed.
A) Sele	ect correct alternative.	
1)	If conductance increases as tem	perature increases, this is known as a
	A) positive coefficient	B) negative current flow
	C) negative coefficient	D) positive resistance
2)	Which of the following cannot act	tually move ?
	A) majority carriers	B) ions
	C) holes	D) free electrons
•	What electrical characteristic of controlled by the addition of impu	of intrinsic semiconductor material is urities?
·		
ŕ	controlled by the addition of impu	ırities?
·	controlled by the addition of impu  A) conductivity	urities ? B) current D) all of the above
4)	controlled by the addition of impu  A) conductivity  C) power	urities ? B) current D) all of the above
4)	controlled by the addition of impu A) conductivity C) power In superconductivity the conduct	urities ? B) current D) all of the above ivity of a material becomes



5)	The temperature at which conductivity of a material becomes infinite is called				
	A) Critical tempo	erature	B) Absolute temp	perature	
	C) Mean temper	rature	D) Crystallization	temperature	
6)	What is a type o				
	A) extrinsic sem	niconductor mate	rial		
	B) pentavalent r				
	<ul><li>C) n-type semic</li><li>D) majority carr</li></ul>				
7)	Minority carriers		activated by		
,,	A) heat	B) pressure	C) dopants	D) forward bias	
8)	,	, .	sidered a semicono	•	
-,	A) carbon	B) ceramic	C) mica	D) argon	
B) Sta	te <b>true</b> or <b>false</b> .				
1)	The solid in which	ch periodicity of a	toms extended thr	oughout the material	
,	is known as amo	-		· ·	
	A) True	B) False			
2)	Lattice + Basis =	= Crystal structui	re		
	A) True	B) False			
3)	The forward volume		ermanium transis	tor is 0.7 V and for a	
	A) True	B) False			
4)	When a depletio large.	n region of a tran	sistor is large, the l	barrier voltage is also	
	A) True	B) False			
5)	The Bravais latt	ice of CsCl crysta	al is body centre.		
	A) True	B) False			
6)	The atomic pack	king fraction of a	b.c.c. lattice is 74°	%.	
	A) True	B) False			

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#### M.Sc. (Part – I) (Semester – I) Examination, 2015 (CBCS Pattern) (New) PHYSICS (Materials Science) Paper – III: Analog and Digital Electronics

	Paper – III : Analog a	•	onics
Day and Date	e : Friday, 20-11-2015		Max. Marks : 70
Time : 10.30	a.m. to 1.00 p.m.		
Instructio	ons: 1) Q. <b>1</b> and <b>2</b> are <b>compuls</b> 2) Answer <b>any three</b> ques 3) <b>All</b> questions carry <b>equ</b> 4) <b>Use</b> of non-programma	tions from Q. <b>3</b> to 0 <b>al</b> marks.	
1. A) Selec	ct the correct alternative :		8
a)	circuit is used as a u ) Voltage follower ) Single ended diff. amplifier	b) Difference ar	mplifier
•	ne voltage gain of a basic instrui ) Diode b) Capacitor	mentation amplifier c) Resistor	
a)	ow many flip flops are required t ) 1 b) 4 ne function of a multiplexer is	o produce a divide- c) 6	-by-128 devices ? d) 7
b) c)	<ul><li>To decode information</li><li>To select 1 out of N input data</li><li>To transmit data on N lines</li><li>To perform serial to parallel co</li></ul>		mit it to single channel
a)	ddress bus of 8085 is ) Unidirectional ) Tri-directional	b) Bidirectional d) Directionless	

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	6)	The practical value a) 30 dB	of CMRR for 74 b) 40 dB	•	o-Amp is 90 dB	d)	25 dB	
	7)	The 7812 regulator a) 5 V	CIC provides b) -5V	c)	12 V	d)	– 12 V	
	8)	Which of the follow a) RAM	ring is non-volatil b) ROM		emory ? SRAM	d)	DRAM	
В	1) 2) 3) 4) 5)	ate <b>true</b> or <b>false</b> : The operational am network. The LM 317 is used The race around county. The ROM in 8085 The differential am Every flip flop is trigon.	d as adjustable no ondition occurs ir is used as a stac plifier is used as	egat n ma k. high	ive voltage reg ster-slave J-K gain direct co	gula flip uple	ator. o-flop. ed amplifier.	<b>6</b>
1) 2)	) Ex	pt the following: plain the phase shif plain effect of feedb plain AND gate usir	ack on closed lo	•	•			14
	dif	plain with neat circu ferent circuit config rite a note on summ	urations.	orkir	ng of differentia	al ar	mplifier using	10 4
,	) Wı	aw the pin configura rite an assembly lan 85 μ p instructions.	•		•			<b>8</b> 9 <b>6</b>
ŕ	wa	th a neat sketch ob ive generator. plain the working of	•			ncy	/ of a square	8
,		sing a suitable logic plain Demorgans th			•		•	8 6
·	SII	hat is a shift registe PO mode of registe educe the following e	r.		-		ation of a 4-bit	8
<b>.</b>	•	$\overline{B} + A\overline{C})(BC + B\overline{C})(AC)$		, 50		,.		6

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#### M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Materials Sci.) (CBCS) Classical Mechanics (New) (Paper – IV)

Day and Date: Monday, 23-11-2015 Total Marks: 70

Time: 10.30 a.m. to 1.00 p.m.

Instructions: 1) Q. 1 and 2 are compulsory.

- 2) Answer any three questions from Q. 3 to Q. 7.
- 3) All questions carry equal marks.
- 4) Use of non-programmable calculator is allowed.
- 1. a) Choose correct alternative:
  - 1) A wheel of mass 5 kg and radius of gyration 40 cm is rotating at 200 rpm. The rotation kinetic energy of the wheel is
    - a) 0.35 J
- b) 3.5 kJ
- c) 0.35 kJ
- d) 3.5 J

2) The force F is non-conservative if,

a) 
$$\oint \mathbf{F} \cdot d\mathbf{r} = 0$$

b) 
$$\nabla \times \mathbf{F} = \mathbf{0}$$

c) 
$$F = -\nabla V$$

d) 
$$\oint \mathbf{F} \cdot d\mathbf{r} \neq 0$$

3) The angular momentum J of system of particles is expressed as,

a) 
$$L = R \times P + L_{CM}$$

b) 
$$L = R \cdot P + L_{CM}$$

c) 
$$L = R \times P - L_{CM}$$

d) 
$$L = P \times R + L_{CM}$$

- 4) A rigid rod of length l is moving freely inside a hallow sphere of radius r, (r > 1) such that it's both ends are always in contact with the inner surface of the sphere. The degrees of freedom of the rod are,
  - a) Four

b) Three

c) Two

d) One



- 5) The square of the period of revolution of a planet around the sun is proportional to,
  - a) cube root of semi-major axis of the ellipse
  - b) cube root of semi-minor axis of the ellipse
  - c) cube of semi-minor axis of the ellipse
  - d) cube of semi-major axis of the ellipse
- 6) For elliptical orbit

a) 
$$E = 0$$
 and  $e = 1$ 

b) 
$$E > 0$$
 and  $e = 0$ 

c) 
$$E < 0$$
 and  $e < 1$ 

d) 
$$E < 0$$
 and  $e > 1$ 

7) The Lagrangian of ideal spring-mass system (mass m is attached to one end of spring of constant k) is

a) 
$$L = \frac{m \dot{x}^2}{2} + \frac{k x^2}{2}$$

b) 
$$L = \frac{m \dot{x}^2}{2} - \frac{k x^2}{2}$$

c) 
$$L = \frac{m \dot{x}^2}{2} + k x^2$$

d) 
$$L = \frac{m \dot{x}^2}{2} - k x^2$$

8) Which of the following relationship holds true for the Poisons beckets between  $p_x$ ,  $L_v$ ?

a) 
$$[p_x, L_v] = z$$

b) 
$$[p_x, L_v] = -z$$

c) 
$$[p_x, L_y] = 0$$

d) 
$$[p_x, L_y] = 1$$

- b) True or False:
  - 1) If the total internal force on the system is zero, its total linear momentum is constant of motion.
  - 2) The generalized momentum corresponding to every generalized coordinate is constant of motion.
  - 3) Under the central force motion, the radius vector sweeps equal area in equal time intervals.
  - 4) In a given Lagrangian L(q, q,  $\dot{t}$ ) if df (q<sub>1</sub>, q<sub>2</sub>, q<sub>3</sub>, ..... q<sub>n</sub>)/dt is added, the Lagrangian equations of motion remain invariant.
  - 5) If F(q, p, t) and G(q, p, t) are constants of motion, then [F, G] is not constant of motion.
  - 6) For elliptical orbit the total energy solely depends on the major axis.

8

8

6



#### 2. Answer in short:

- a) Keplers Third Law of planetary motion. 5
- b) Derive Jacobi Integration. 5
- c) D'Alembert's principle.
- 3. a) Derive Eular Lagrangian differential equation.
  - b) Using the technique of calculus of variation, show that the distance between two points in a plane is shortest.
- 4. a) Find the Hamiltonian corresponding to the Lagrangian  $L(\dot{q}) = (1 \dot{q}^2)^{1/2} (|\dot{q}| \le 1)$

and Lagrangian corresponding to Hamiltonian 
$$H(p, q) = \left(\frac{1}{2}p^2 + p \sin q\right)$$
.

- b) State and prove the Poison's theorem.
- 5. a) Show that the transformation defined as
  - $P=2\left(1+q^{1/2}\cos p\right)q^{1/2}\sin p$  and  $Q=\log\left(1+q^{1/2}\cos p\right)$  is canonical. Find the corresponding generating function.
  - b) Write the Hamiltonian for a simple pendulum and deduce the Hamiltonian canonical equations of motion.
- 6. a) Explain the reduction of two body problem in to one body problem.
  - b) Find  $[L_x, L_y]$  and  $[L_x, P_y]$ .
- 7. a) Discuss Rutherfords scattering theory of unbounded motion.
  - b) Write a note on differential cross-section.

Seat No.

#### M.Sc. (Part – I) (Semester – I) (Old-CGPA) Examination, 2015 PHYSICS (Material Science)

Paper - I: Mathematical Techniques

Day and Date: Monday, 16-11-2015 Total Marks: 70

Time: 10.30 a.m. to 1.00 p.m.

Instructions: 1) Q. No. 1 and Q. No. 2 are compulsory.

- 2) Answer any three questions from Q. No. 3 to Q. No. 7.
- 3) **Use** of Non-Programmable Calculator is allowed.
- 4) All questions carry equal marks.
- 1. a) Choose the correct alternative:

i) The Cauchy Riemann equations are for the analytic function

$$f(z) = v + iu$$
 are

A) 
$$v_x = u_v$$
 and  $u_x = -v_v$  B)  $u_x = v_v$  and  $v_x = u_v$ 

B) 
$$u_x = v_v$$
 and  $v_x = u_v$ 

C) 
$$u_x = -v_y$$
 and  $v_x = u_y$  D)  $u_x = u_y$  and  $v_x = v_y$ 

D) 
$$u_x = u_y$$
 and  $v_x = v_y$ 

ii) A function v is said to be Harmonic if it satisfy

A) 
$$v_{xx} + u_{yy} = 0$$

B) 
$$v_{xy} - u_{xy} = 0$$

C) 
$$v_{xx} + v_{yy} = 0$$

$$D) u_{xy} - v_{xy} = 0$$

iii) The particular solution of the ordinary differential equation is the solution obtained by putting particular values to

- A) Dependent variable
- B) Independent variable
- C) Arbitrary constants
- D) All of the above

iv) The vectors [0, 1,0], [1, 0, -1], [1, 0, 1] are

- A) Linearly independent
- B) Linearly dependant
- C) Orthogonal
- D) Linearly independent and orthogonal



- v) The Fourier series of f (x) in (-a, a) will involve \_\_\_\_\_ if f (x) is even.
  - A) Only cosine terms
- B) Constants
- C) Both sine and cosine terms
- D) Only sine terms
- vi) The vectors  $X_1$ ,  $X_2$  and  $X_3$  are said to be orthogonal if

A) 
$$X_1 \cdot X_2 = 0$$
,  $X_2 \cdot X_3 = 0$  and  $X_3 \cdot X_1 = 0$ 

B) 
$$X_1 \cdot X_2 = 1$$
,  $X_2 \cdot X_3 = 1$  and  $X_3 \cdot X_1 = 1$ 

C) 
$$X_1 \cdot X_2 = X_3$$
,  $X_2 \cdot X_3 = X_1$  and  $X_3 \cdot X_1 = X_2$ 

- D) None of the above
- b) State true or false:

- i) The value of the integral  $\int_{c} \frac{dz}{z^2 2z} c : |z| = 1$  is 0.
- ii) Fourier series of the function exists if it satisfy continuity condition.
- iii) Laplace transform is derived from Integral Transform by taking t < 0.
- iv) Cosecx cannot be expressed as Fourier series in  $(-\pi, \pi)$ .
- v) Fourier cosine transform of  $\frac{1}{x}$  is  $\sqrt{2/\pi}$  .
- vi) If  $L\{f(t)\}=\phi(s)$  then  $L\{e^{-at} f(t)\}=\phi(s+a)$ .
- vii) If the vectors are linearly independent then one vector can be expressed as linear combination of others.
- viii) A differential equation is said to be linear if the dependent variable is having degree atmost one and they are not in multiplication.
- 2. Write short notes on:
  - a) State and explain Cauchy Residue theorem with an example.

5

b) Define Orthogonal and Unitary matrices.

4

c) Write a note on Integral Transform.



- 3. a) Show that the function  $u = x^2 y^2$  and  $v = \frac{y}{x^2 + y^2}$  are harmonic, but they are not harmonic conjugates of each other.
- 8
- b) Find the eigen values and eigen vectors corresponding to negative eigen
  - values  $\begin{pmatrix} 2 & 1 & 1 \\ 2 & 3 & 2 \\ 3 & 3 & 4 \end{pmatrix}$ .
- 4. a) Solve  $(2x-1)^3 \frac{d^3y}{dx^3} + (2x-1)\frac{dy}{dx} + (-2y) = 0$ .
  - b) Find the Fourier Series of  $f(x) = x^3$  in  $[-\pi, \pi]$ .
- 5. a) Define Laplace transform and hence find Laplace transform of  $\int_{0}^{t} e^{-u} u^{3} du$ . 8
  - b) Use Cauchy Integral formula to evaluate  $\int_C \frac{4-3z}{z(z-1)(z-2)} dz$  where C is the circle |z|=3/2.
- 6. a) Define adjoint of the matrix. Hence find  $A^{-1}$  of the matrix using adjoint matrix
  - method for  $\begin{pmatrix} 2 & 5 & 3 \\ 3 & 1 & 2 \\ 1 & 2 & 1 \end{pmatrix}$ .
  - b) Solve  $(D^4 + 8 D^2 + 16)y = \sin^2 x$ .
- 7. a) Express the function,  $f(x) = \begin{cases} 1, & |x| < 1; \\ 0, & |x| > 1 \end{cases}$ . Hence evaluate  $\int_{0}^{\infty} \frac{\sin \omega \sin \omega x}{\cos \omega} d\omega$ . 8
  - b) Evaluate the integral using Laplace transform method  $\int_{0}^{\infty} \frac{e^{-at} e^{-bt}}{t} dt$ .



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## M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Materials Science)

	PRISICS (Mate Paper – II ( Condensed M	Old-CGPA)		
Day and Date: Wed	Inesday, 18-11-2015		Max. Marks : 70	)
Time: 10.30 a.m. to	o 1.00 p.m.			
Instructions:	<ol> <li>Attempt five question</li> <li>Q. 1 and Q. 2 are con</li> <li>Attempt any three from the right</li> <li>Use of non-scientification</li> </ol>	<b>mpulsory</b> . rom Q. <b>3</b> to Q. <b>7</b> . indicate <b>full</b> marks		
1. A) Select corre	ect alternative :		8	8
1) Atomic r	adius (r) of the atom in F	CC structure is		
a) $\frac{a}{2\sqrt{2}}$	b) $\frac{a}{\sqrt{3}}$	c) $\frac{a}{4\sqrt{3}}$	d) $\frac{a}{\sqrt{2}}$	
a) (0 0 1	, , , ,	c) (0 1 0)		
3) Dielectri	c power loss is given by t	he relation		
a) V <sup>2</sup> ω	c cos(90 - φ)	b) V² jωc si	n(90 – ф)	
c) V² jα	oc sinφ	d) V² j∞c co	os(90+ \phi)	
<ol> <li>4) Dielectrie</li> <li>a) 2</li> </ol>	c constant of air is b) 0.5	c) 0	d) 1	
	tion is said to be effective age thermal energy is	e, if the ratio of ave	rage dipole energy to	
a) < 1	b) > 1	c) = 1	d) = 0	
, .	neat of superconductor sho		•	
a) = 0	b) $< T_c$	c) > T <sub>c</sub>	d) = Tc	

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7)	Electric susceptibili	ty is given by the r	elation		
	a) P/E	b) $\frac{E}{4\pi}$	c) E/P	d) $\frac{(\epsilon-1)E}{4\pi}$	
8)	Packing fraction of	FCC structure is			
	a) 74%	b) 68%	c) 52%	d) 69%	
1) 2) 3) 4) 5)	tate <b>true</b> or <b>false</b> : Impedance is nothin Lattice constant is leading frequency of x-ray Ewald sphere is dro Effective mass is grant addition of pent	ess than atomic rais around 10 <sup>18</sup> to sown with a diamete reater than real ma	idius. 10 <sup>20</sup> Hz. r 1/λ . ass.	miconductor.	•
2. Atten	npt following :				14
1) CI	lausius-Mosotti equat	tion.			5
-	chottky effect.				5
3) Pe	enetration depth $(\lambda)$ .				2
	hat is superconductorite about direct and i			ssner's effect.	10
4. a) W	hat is dielectric polari	zation ? Give the e	expression for Lo	rentz internal field.	10
b) Ex	xplain complex dielec	ctric constant of so	lid.		4
•	hat is reciprocal lattic		-		10
	ive the elementary co norphous materials.	oncept of poly crys	talline, nano crys	stalline and	4

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b) Calculate London penetration depth of mercury at 5 K, Given  $\lambda$  at 0 K = 30 nm

10

4

10

4

6. a) What is extrinsic semiconductor? Write the expression for carrier

concentration in n-type semiconductor.

7. a) Write the thermodynamics of superconductor.

and Tc = 4.12 K.

b) Explain Josephson's effect.

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M.Sc. (Part – I) (Semester – I) Examination, 2015
PHYSICS (Master Scien.) (Old-CGPA)
Paper – III: Analog and Digital Electronics

	Paper – III : Anai	og and Digital Ele	ctronics	
Day and Date: F Time: 10.30 a.m	Friday, 20-11-2015 n. to 1.00 p.m.		Total Marks : 70	)
	nctions: 1) Q. <b>1</b> and ( 2) Attempt <b>a</b>	Q. <b>2</b> are <b>compulsory</b> Iny three from Q. <b>3</b> to o <b>right</b> indicate <b>full</b> m	Q. <b>7</b>	
1. a) Select co	orrect alternative :		<b>{</b>	8
groun a) vo c) po 2) The c a) sm b) eq c) gre	nd is only a Itage reference	b) current refe d) difference r gain is roltage gain		
a) Hiç	gh CMRR	b) High outpu		
4)	ack loop, for a phase-s	total phase shift re	quirement, around the	
5) Decin a) 6	nal value of binary 100 b) 9	10 is c) 18	d) 20	

6) The register in the 8085A that is used to keep track of the memory address



		ŕ	of the next op-co a) stack pointer c) accumulator	de to be run in the	b)	_	is the am counter	
		7)	A differentiator is a) the sum of the b) the difference c) the area unde d) the rate of cha	e input voltage between two volt er a curve	age			
		8)	The lead-lag circu at which the atter a) 1/2			oscilla 1/4	tor has a resonant frequency d) 1/5	
	b)	Sta	ate whether the fo	llowing are <b>True</b>	or <b>F</b>	alse:		6
		1)	8085 microproce	ssor has 14-bit a	ddre	ess bu	S.	
		2)	The output voltaginput voltages.	e of a summing a	mp	lifier is	proportional to the sum of the	
		3)	8085 microproce	ssor has 1k of int	ern	al RON	Л.	
		4)	The open loop gaused in the electron		dep	ends (	on the values of the resistors	
		5)	LC feedback ele greater than 1 Mh		ally	used i	n oscillators for frequencies	
		6)	A reliable method	d for eliminating o	lecc	oder sp	ikes is to use strobing.	
2.	Ex	pla	in <b>any three</b> of the	e following :				14
	1)	De	emultiplexer					
	2)	Sy	nchronous counte	er				
	3)	Op	o-amp used as diff	erentiator				
	4)	LC	tunable oscillator	·.				
3.	a)	Sta	ate and explain the	e characteristics	of a	n Idea	l Op-Amp.	8
	b)		hat are the factors set current?	that affect the in	put	offset	voltage, input bias and input	6



4.	a)	With the help of neat labelled diagram explain RC phase shift Oscillator. Explain its operation. Write its merits and demerits.	8
	b)	Draw the circuit of square wave generator using an op-amp. Explain the operation of circuit drawing output waveform.	6
5.	a)	Draw the logic circuit of R-S flip flop using NOR gate. Explain its operation by using state transition table.	8
	b)	What is D flip-flop? Describe how the JK flip flop is realized. What is its advantage over RS flip-flop?	6
6.	a)	Explain the function of following in 8085 microprocessor:  i) Flags  ii) Accumulator  iii) Program counter  iv) Stack pointer	8
	b)	Write a program in 8085 assembly language to divide two 8-bit numbers stored in consecutive memory locations.	6
7.	a)	What is switching regulator? List four major component of switching regulator.	8
	b)	Define the CMRR and explain the significance of relatively large value of CMRR.	6

Seat No.

> M.Sc. (Part – I) (Semester – I) Examination, 2015 **PHYSICS (Materials Science)** Paper – IV : Classical Mechanics (Old – CGPA)

Max. Marks: 70 Day and Date : Monday, 23-11-2015

Time: 10.30 a.m. to 1.00 p.m.

**Instructions**: 1) Question 1 and 2 are compulsory.

2) Attempt any 3 from Q. 3 – Q. 7.

3) Figures to the right indicate full marks.

1. a) Choose correct alternative:

1) If N = dL/dt = 0, where N is the torque and L, the angular momentum, then which of the following is conserved?

a) Torque

b) Angular momentum

c) Linear momentum

d) Energy

2) If the Hamilton's principal function is  $S = 2\alpha \left[ (\cos^2(\omega t + \beta) - 1/2), \text{ then the} \right]$ Lagrangian, L is

a) 
$$L = 2\alpha (\cos^2 (\omega t - \beta) + 1/2)$$
 b)  $L = 2\alpha (\cos^2 (\omega t + \beta) - 1/2)$ 

b) 
$$L = 2\alpha (\cos^2 (\omega t + \beta) - 1/2)$$

c) 
$$L = 2\alpha (\cos^2 (2\omega t + \beta) - 1/2)$$
 d)  $L = 2\alpha (\cos^2 (2\omega t + \beta) + 1/2)$ 

d) 
$$L = 2\alpha (\cos^2 (2\omega t + \beta) + 1/2)$$

3) Constraints introduce which of the following difficulties in the solution of mechanical problems?

- a) The coordinates are no longer all independent
- b) The force of constraint is not furnished a priori
- c) Both (a) and (b)
- d) None of the above



- 4) In a central force motion, if the circular orbit is stable, then a small increase in the particle energy above the value for a circular orbit results in
   a) A drastic variation of the orbital radius
  - b) Constancy of the orbital radius
  - c) Only a slight variation of orbit radius
  - d) A large variation of orbit radius
- 5) The physical quantities defined without reference to a set of generalized principles is a merit of
  - a) D' Alembert' s principle

b) Variational principle

c) Hamilton's principle

- d) Lagrange's principle
- 6) A monogenic system refers to the motion of those mechanical systems for which all forces are derivable from a generalized scalar potential that may be a function of
  - a) Coordinates

b) Velocities

c) Time

- d) All of the above
- 7) Under canonical transformations,  $F_2 = q_i P_i$ ,  $Q_i = q_i$  and  $P_i = p_i$  correspond to which of the following generating function?

a) 
$$F = F_2 (q, P, t) - Q_i P_i$$

b)  $F = F_3 (p,Q,t) + q_i p_i$ 

c)  $F = F_1 (q,Q,t)$ 

- d)  $F = F_4 (p,P,t) + q_i p_i Q_i P_i$
- 8) The fundamental Poisson brackets are \_\_\_\_\_ under canonical transformations.
  - a) Variant

b) Invariant

c) Jacobian

d) Partial derivatives

b) True/False:

- 1) Holonomic constraints can be put in an equation form.
- Constraints cannot introduce restrictions in the motion of a mechanical system.
- 3) According to Kepler's laws of planetary motion, the square of the periods of the various planets are proportional to the square of their major axes.



- 4) In Rutherford's scattering, the scattering angle is a smooth monotonic function of the impact parameter.
- 5) As per Euler's theorem, the general displacement of a rigid body with one point fixed is a rotation about some axis.
- 6) If coordinates are cyclic in a Lagrangian, then they are also cyclic in a Hamiltonian.

2.	Wı	rite short answers ( <b>any three</b> ) :	14
	a)	Deduce the work-energy theorem.	5
	b)	Explain briefly the general analysis of orbits.	4
	c)	Explain the principle of least action.	5
	d)	What are the conditions for the transformation to be canonical? Explain.	4
3.	a)	State the conservation of energy for a single particle system.	4
	b)	Prove conservation of linear and angular momentum for a single particle system.	10
4.	a)	What is meant by virtual work? Explain D' Alembert's principle.	6
	b)	Obtain the Lagranges equation of motion for Atwood's machine.	8
5.	a)	Set up the equations of canonical transformation.	6
	b)	Prove that the transformation $Q_1 = q_1$ , $P_1 = p_1 - 2p_2$ , $Q_2 = p_2$ , $P_2 = -2q_1 - q_2$ is canonical and find a generating function.	8
6.	a)	Explain Jacobian identity.	4
	b)	Obtain Hamilton's canonical equations in Poisson bracket notations.	10
7.	a)	Explain why Hamilton's formalism is called an integral formalism?	6
	b)	Describe any one example of Hamilton's equation of motion.	8



Seat	
No.	

## M.Sc. (Part – I) (Semester – II) (New CGPA) Examination, 2015 PHYSICS (Materials Science) Paper – V : Statistical Mechanics

	ı	Paper – V : Stat	tistical Mechanics	5	
•	ate : Tuesday, 30 a.m. to 1.00			Total Marks :	70
Insti	2) A 3) <b>A</b>	O. <b>1</b> and Q. <b>2</b> are <b>co</b> attempt <b>any three</b> to A <b>ll</b> questions carry Tigures to the <b>right</b>	from Q. <b>3</b> to Q. <b>7</b> .		
1. A) Ch	noose the corre	ect alternatives :			8
i)	μ-space for a	single particle is _			
	a) two dimens	sional	b) three dimension	al	
	c) six dimens	ional	d) dimensionless		
ii)	If the system i through the sy	•	te, following three qu	antities are constant	
	a) T, S, P	b) Τ, S, μ	c) Τ, Ρ, μ	d) $\mu$ , P, S	
iii)	ldeal gas is or	ne for which mutua	l interaction betweer	n the molecules is	
	a) high	b) negligible	c) zero	d) repulsive	
iv)	In B.E. statisti	cs, particles are			
	a) distinguish	able	b) indistinguishable	е	
	c) dimension	less	d) weightless		
v)	_		thermal expansion is		
	a) $S_{2} - S_{1}$	b) T $(S_2 - S_1)$	c) R log $(V_2/V_1)$	d) Q/T	
vi)		aw of thermodyna	mics is the law of con	servation of energy.	
	a) 0 <sup>th</sup>	b) 1 <sup>st</sup>	c) 2 <sup>nd</sup>	d) 3 <sup>rd</sup>	
vii)	Phase space I	nave	dimensions.		
	a) N	b) 6N	c) 3N	d) 2N	
viii)	Sakur-tetroid	formula gives the re	elation for		
	a) entropy	b) enthalpy	c) internal energy	d) Gibb's energy	

#### **SLR-MM - 398**

B) **True** or **false**:



6

		i) At critical point $g_1 = g_2 \neq g_3$ .	
		ii) In grand canonical ensemble, system exchanges both energy and matter.	
		iii) Diffusion is reversible process.	
		iv) Liouvilles equation gives the rate of change in temperature.	
		v) Critical indices are nothing but the reduced indices.	
		vi) As per Bose Einstein condensation, if $T \rightarrow 0$ , No $\rightarrow N$ .	
2.	At	tempt any three of the followings:	14
	a)	Explain phase transition using P-T diagram.	
	b)	Give the law of corresponding states.	
	c)	Nernst heat theorem.	
	d)	Microstates and macrostates.	
3.	Ar	swer the followings :	
	a)	Derive the Einstein's equation of Brownian motion.	8
	b)	Discuss the Fluctuation dissipation theorem.	6
4.	a)	Discuss the laws of thermodynamics.	6
	b)	Derive the expression for entropy of mixing of different gases.	8
5.	a)	Give in detail the expression for classical ideal gas.	8
	b)	Derive Clausius-Clapeyron's equation.	6
6.	a)	Derive the condition for phase equilibrium.	6
	b)	Give the expression for critical indices.	8
7.	a)	What is micro canonical ensembles? Give the condition for equilibrium between two system in thermal contact.	6
	b)	Write about Boltzmann's canonical distribution law $ni=Ae^{-\beta\epsilon i}$ .	8

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Seat	
No.	

M.Sc. (Part – I) (Semester – II) Examination, 2015 **PHYSICS (Material Science)** Paper – VI: Quantum Mechanics (New – CGPA)

Day and Date: Thursday, 19-11-2015 Max. Marks: 70

Time: 10.30 a.m. to 1.00 p.m.

Instructions: i) Q. (1) and Q. (2) are compulsory.

- ii) Attempt any three questions from Q. (3) to Q. (7).
- iii) All questions carry equal marks.
- iv) Figures to right indicate marks.
- 1. A) Choose the correct alternative:

i) Which of the following is a Hermitian operator?

- a)  $\frac{\partial}{\partial t}$  b)  $-\frac{\partial}{\partial x}$  c)  $\frac{\partial^2}{\partial t \partial x}$  d)  $i\frac{\partial}{\partial t}$

ii) If potential is symmetric then the wave function of a particle will be

- a) symmetric
- b) antisymmetric
- c) either symmetric or antisymmetric
- d) neither symmetric nor antisymmetric

iii) If  $\,\psi_1$  and  $\,\psi_2$  are two states defined by

$$\psi_1 = \phi_0 - 2\phi_1 + 3\phi_2$$

$$\psi_2 = \phi_0 - \phi_1 + \alpha \phi_2$$

where,  $\alpha$  is constant. The value of  $\alpha$  for which  $\psi_1$  is orthogonal to  $\psi_2$  is

- a) 2
- b) 1
- c) -1
- d) -2

iv) The spectrum of hydrogen atom has

- a) discrete energy levels which are equally spaced
- b) a ground state which is degenerate
- c) a ground state which shows minimum uncertainty
- d) degenerate excited states

v) The ground state wave function of a linear harmonic oscillator



	<ul> <li>a) has exactly one node</li> <li>b) is Gaussian in momentum space</li> <li>c) is an eigen state of position operator</li> <li>d) has odd parity</li> <li>vi) If two observables A and B can be simultaneously measured, then</li> <li>a) [A, B] = 0</li> <li>b) A = B<sup>+</sup></li> <li>c) Commutator of A and B is unit operator</li> <li>d) None of these</li> </ul>	
	B) Write <b>true</b> or <b>false</b> :  vii) The radial part of the wave functions of the hydrogen atom is expressed in terms of Legendre polynomials.	4
	viii) The parity of a wave function $\psi(x) = \sin x$ is odd.	
	ix) The first Bohr radius is $5  \mathring{\text{A}}$ .	
	x) The average nuclear charge decreases for a electron having large I values.	
	C) Fill up the blanks:  xi) As per Pauli principle an orbital can accommodate 2 electrons having the spins  xii) The momentum operator in x dimension is  xiii) In a DeBroglie relation momentum is given by	4
	xiv) Nitrogen atom has p electrons.	
2.	Attempt <b>any three</b> of the following:  a) What are the properties of an acceptable wave function?	14
	b) Show that the commutate bracket $\left[x^2, \frac{d}{dx}\right]$ is equal to -2.	
	c) For hydrogen atom show that the maximum radial density occurs at a distance ${\bf a}_0$ where ${\bf a}_0$ is Bohr radius.	

d) Write the Hamiltonian for many electron atom and explain it.



3. a) A one dimensional box is defined by a potential v = 0 for 0 < x < a and  $v = \infty$ for x < 0 and x > a where a is width of a box. Obtain the solutions and normalized eigen function. 10 b) Show that the longer wavelengths depend on larger width of a box. 4 4. a) Solve the following equation to get E 10  $\frac{\partial^2 \psi}{\partial x^2} + \frac{8 \pi^2 m}{h^2} \left( E - \frac{1}{2} k x^2 \right) \psi = 0$ b) Obtain the normalized  $\psi$  of above equation and show them on a diagram along with energy levels. 4 5. a) Write the Schrodinger equation for hydrogen like atom in spherical polar co-ordinates and separate the three equations exclusive functions of  $\phi$ ,  $\theta$  and r. 4 b) Solve the radial part to get the expression for energy. 10 6. a) Set up a Hamiltonian for helium atom using the slater determinant, overall wave function and using the minimization of energy. Obtain the ground state energy of the helium atom. 10 b) State and explain Heisenberg's uncertainty principle. 4 7. a) Describe the LCAO approximation and discuss the secular equation. 6

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b) Write a note on Slater's rules.

Seat No.

#### M.Sc. – I (Semester – II) Examination, 2015 PHYSICS (Materials Science) (New-CGPA)

Paper - VII: Electrodynamics

Day and Date: Saturday, 21-11-2015

Total Marks: 70

Time: 10.30 a.m. to 1.00 p.m.

Instructions: 1) Q. 1 and 2 are compulsory.

2) Answer any three questions from Q. 3 to Q. 7.

3) All questions carry equal marks.

1. Objective questions.

14

A) Choose correct alternative

8

1) Work done per unit charge by the source is

a) EMF

b) MMF

c) Poynting's vector

d) Potential

2) As per the second law of reflection, angle of incidence is equal to

a) 
$$\theta i = 0$$

b) 
$$\theta i = \theta r$$

c) 
$$\theta i < \theta r$$

d) 
$$\theta i > \theta r$$

3) Maxwell's corrections to Ampere's circuital law is

a) 
$$div B = 0$$

b) curl 
$$E = -\frac{\partial B}{\partial t}$$

c) curl H = J + 
$$\frac{\partial D}{\partial t}$$

d) div 
$$D = \rho$$

4) The law of conservation of energy for EM waves is

a) 
$$T \times R = 1$$

b) 
$$T - R = 1$$

c) 
$$\frac{T}{R} = 1$$

d) 
$$T + R = 1$$

4) Polarization of EM wave.



	5	5) Minkowski is a	dimensional	space.	
		a) One, scalar and ve	ctor b)	Four, real scalar	
		c) Four, real vector	d)	All of these	
	6	6) Magnetic vector potepotential.	ntial 'A' and sc	alar potential 'ø' are related to	
		a) Hertz	b)	Coulomb	
		c) Lorentz	d)	None of these	
	7	7) Potential function 2x <sup>2</sup>	+ 2y <sup>2</sup> + 2z satisfy	equation.	
		a) $\nabla^2 \phi = 0$	b)	$\nabla^2\varphi\neq 0$	
		c) $\nabla^2 \phi = \rho / \epsilon_0$	d)	All of these	
	8	B) Radiation resistance for	or half wave ante	nna isohms.	
		a) 70	b)	70.2	
		c) 73.2	d)	71.2	
	B) 1	Γrue/False :			6
	1	<ol> <li>In case of oblique incident wave.</li> </ol>	idence transmitte	ed wave is always in phase with	
	2	2) Electromagnetic wave	s are transverse	in nature.	
	3	3) $\frac{\partial \rho}{\partial t} = J$			
	4	<ol> <li>The total power radiate according to law of cor</li> </ol>	· · · · · · · · · · · · · · · · · · ·	t of radius of the sphere, which is	
	5	5) Thomson scattering is	an important phe	enomenon in plasma physics.	
	6	6) All Maxwell's equation	s are homogenou	IS.	
2.	Write	e the short notes (any thr	ree) :		<b>1</b> 4
	1) F	Radiation damping			
	2) 5	Skin depth			
	3) F	araday's law for stationa	ıry media		



3.	a)	Explain Poynting's theorem.	8
	b)	Show that momentum density is related to Poynting's vector.	6
4.	a)	Give the relations in quasistationary electric and magnetic systems.	8
	b)	Give the interaction between two current loops.	6
5.	a)	Write the field equations for the electromagnetic waves passing through the conductor.	8
	b)	Write the Maxwell's correction to Ampere's theorem.	6
6.	a)	What is retardation? Write the solution of in-homogenous wave equation on the basis of retarded and advance potential.	10
	b)	Explain Maxwell's in homogenous and homogenous wave equations.	4
7.	a)	What is radiation emission? Explain radiation from half wave antenna.	10
	b)	Explain the wave equation in terms of electromagnetic potential.	4

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**SLR-MM - 401** 

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Seat	
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·	PHYSICS (Ma	(New CGPA) Examina terials Science) alytical Techniques	tion, 2015
Day and Date : Tuesda Fime : 10.30 a.m. to 1.			Total Marks : 70
Instructions	3) <b>All</b> questions c	<b>ree</b> questions from Q. <b>3</b> to	
1. Objective question	IS.		(14)
a) Select correct	alternatives.		8
1) X-rays pen	etrate human body a	and matter because it is	radiation.
a) Electror	nagnetic radiation	b) Longer wavelength	
c) Shorter	wavelength	d) Invisible	
2) The energy	of X-rays depend up	oon the	
a) Acceler	ation voltage	b) Heater current	
c) Anode o	current	d) Heater voltage	
3) Which of th	ne following is not a s	source of visible radiation?	•
a) Deuterio	ım lamp	b) Tungsten lamp	
c) Xenon a	arc lamp	d) None of the above	
4) XPS is prin	narly used for		
a) Binding	energies	b) Surface morphology	
c) Thickne	ess	d) Optical band gap	
5) The energy	corresponding to th	e wavelength 516 nm is	
a) 2.40 eV		b) 3 eV	
c) 3.40 eV		d) 2.2 eV	



- 6) IR spectroscopy is helpful for
  - a) Identification of organic compound
  - b) Following progress of a reaction
  - c) Both a) and b)
  - d) None of the above
- 7) Which type of scattering results in a longer wavelength than the incident light?
  - a) Rayleigh

b) Stokes

c) Anti-stokes

- d) All of the above
- 8) The fingerprint region in the IR spectrum is
  - a)  $900 1400 \text{ cm}^{-1}$
- b)  $12500 400 \text{ cm}^{-1}$

c)  $600 - 50 \text{ cm}^{-1}$ 

d)  $660 - 4000 \text{ cm}^{-1}$ 

b) State true or false.

6

- 1) Bremsstrahlung radiation has maximum photon energy in keV numerically equal to the applied kVp.
- 2) X-ray Photoelectron Spectroscopy (XPS) is a widely used technique to investigate the chemical composition of surfaces.
- 3) Fourier transform Raman technique is used to give a stronger signal than normal Raman spectroscopy.
- 4) The main technique used to calculate the band gap of a material is NMR spectroscopy.
- 5) Nitrogen molecules is IR active.
- 6) Alkyl halide material is used for the sample preparation in FTIR.
- 2. Write short notes.

(14)

1) What are the following observations in XPS?

- 1) Photoelectron lines
- 2) Auger lines
- 3) Satellites peaks
- 4) Chemical shift and
- 5) Plasmon loss.
- 2) What are the applications of UV-Vis-NIR spectroscopy?

- 5
- 3) What is Bragg's Law? Derive the relation with appropriate ray diagram.
- 4



3.	a)	Describes the instrumentation and working of double beam UV-Vis absorption spectrometer.	8
	b)	Draw the block diagram of XPS and explain the function of each component in brief.	6
4.	a)	How the lattice parameters of tetragonal and hexagonal structure are determined? Explain with an appropriate diagram and derivations.	10
	b)	The transmittance of a 0.015 mol dm aqueous solution of the [Cu(NH)] ion was measured to be 0.84 at 600 nm through a cuvette of optical path length 1.0 mm. Determine the molar absorption coefficient.	4
5.	a)	Explain the coupled mode and grazing angle XRD with an appropriate diagram.	8
	b)	Give a brief account of qualitative and quantitative applications of Fourier Transform Infra Red (FTIR) spectroscopy.	6
6.	a)	State Beer Lamberts Law and give instrumentation of IR spectrometer.	10
	b)	The longest wavelength absorption in the UV visible spectrum of acetone, CH COCH, occurs at 335 nm. Predict the energy required to excite an electron from a lone pair orbital on the oxygen atom to an antibonding orbital centered on the carbonyl group.	4
			7
7.	a)	What is the importance of Raman spectroscopy? What the stokes and anti-stokes line indicate in the Raman spectra?	8
	b)	Explain the basic crystal structure with their conditions and diagrams.	6

#### **SLR-MM - 402**

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No.	

#### M.Sc. (Part – I) (Semester – II) (CGPA) Examination, 2015 **PHYSICS (Materials Science)**

Paper - V: Statistical Mechanics (Old)

	- 1		(	- · ,		
Day and D	Date : Tuesday, 17	7-11-2015		Total Marks	: 7C	
Time: 10.	30 a.m. to 1.00 p	.m.				
	Instructions: 1	) Attempt <b>five</b> qu	iestions.			
	2	) Q. <b>1</b> and Q. <b>2</b> a				
	3	3) Attempt any three from Q. 3 to Q. 7.				
	4	4) Figure to <b>right</b> indicates <b>full</b> marks.				
1. A) Cł	noose correct alte	rnative :			8	
1)	How much dimer	nsion phase spac	e has			
	a) N	b) 3 N	c) 6 N	d) 2 N		
2)	When system is through the system		te, which quantities	s will remain constant	t	
	a) T, P, K	b) Τ, Ρ, μ	c) T, P, D	d) T, P, η		
3)	Which law of the a) 0 <sup>th</sup>	rmodynamics is t b) 1 <sup>st</sup>	the law of conserva c) 2 <sup>nd</sup>	ation of energy d) 3 <sup>rd</sup>		
4)	The chemical po	tential photon ga	s (μ) is			
	a) $\mu > 0$	b) $\mu$ < O	c) $\mu = 0$	d) $\mu = \infty$		
5)	Pressure at critica) 3 b	•	c) 3b/27Rb	d) 8a/27Rb		
6)	For which gas m a) Real gas		between the moled c) Ideal gas			
7)	In micro canonic a) TVN	al ensemble follo b) EVN	wing parameters rec) EVT	emains constant. d) EVμ		
8)	In F.D. statistics a) distinguishab c) dimension les	le	b) indistinguisha d) weightless		Р.Т.О	

### **SLR-MM - 402**

b) State true/false:



6

		1) Clausius-Clapeyron's equation gives the change of temperature with pressure.	
		<ol><li>In microcanonical ensample, large number of systems having EVT Constant.</li></ol>	
		3) Sakur-tetroid relation is related with the entropy.	
		4) Critical temperature is the highest temperature at which the gas can be liquified by increasing the pressure alone.	
		5) For canonical ensemble temperature is not constant.	
		6) The phase equilibrium curve between solid and gas is the fusion curve.	
2.	Att	empt following :	14
	a)	Canonical ensemble.	5
	b)	P-T diagram of the phase transition.	4
	c)	Classical ideal gas.	5
3.	A)	Derive Clausius-Clayperon's equation.	8
	B)	Derive conditions for phase equilibrium.	6
4.	A)	Explain Gibb's grand canonical distribution.	8
	,	Calculate the increase in entropy when 746 gm water is converted in to vapor at 100°C (The latent heat of vaporization of water is 540 cal/gm.)	6
5.	A)	Derive Ehrenfest's equation.	8
	B)	Explain the difference between micro canonical and grand canonical ensembles.	6
6.	A)	Explain fluctuation dissipation theorem.	8
	B)	What is the density matrix ?	6
7.	A)	Give the condensation for Ideal Bose gas.	10
	B)	Discuss the Boltzmann's limit for Bosons and Fermions.	4

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Seat	
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# M.Sc. – II (Semester – III) Examination, 2015 PHYSICS (Materials Science) (New CGPA) Paper – IX: Semiconductor Devices

'	rapei – IX . Seillicollado	tion Devices	
Day and Date: Monda Time: 2.30 p.m. to 5.0		Max. Marks	: 70
Instructions :	<ol> <li>Attempt five questions.</li> <li>Q. 1 and Q. 2 are computed</li> <li>Attempt any three out of</li> <li>Use of nonprogrammable</li> </ol>	<sup>c</sup> Q. <b>3</b> – Q. <b>7</b> .	
1. Choose the correct	ct alternative :		14
1) In the linear reg	gion power MOSFET's have $\_$	I/P impedance	
a) In terms of	Ohms	b) In terms of K-Ohms	
c) In terms of	M-Ohms	d) In terms of m-Ohms	
2) In TFT, the cha	annel layer is		
a) Polycrystall	line Si	b) Polycrystalline GaAs	
c) Monocrysta	alline Si	d) Monocrystalline GaAs	
3) A simple pn-jur	nction diode in which both p a	nd n are degenerate is	
a) Tunnel diod	е	b) Schottky diode	
c) Gunn diode		d) Zener diode	
4) Burried channe	el CCD has a transfer inefficie	ncy of	
a) $10^{-1} - 10^{-2}$		b) 10 <sup>-2</sup> – 10 <sup>-3</sup>	
c) $10^{-3} - 10^{-4}$		d) $10^{-4} - 10^{-5}$	
<ol><li>In the active reg biased.</li></ol>	gion of a transistor, base to coll	ector junction is always	
a) Forward		b) Reverse	
c) Forward-Re	everse	d) Requires no bias	



- 6) The NDR is due to field induced transfer of conduction band electrons from \_\_\_\_\_ to \_\_\_\_\_ satellite valeys.
  - a) Low energy high mobility, high energy low mobility
  - b) Low energy low mobility, high energy low mobility
  - c) Low energy low mobility, low energy low mobility
  - d) Low energy low mobility, low energy high mobility
- 7) Filling the potential well by the carriers causes surface potential to
  - a) decrease
  - b) increase
  - c) remains unaffected
  - d) gets converted into some another form
- 8) For a MIS-diode the capacitance due to \_\_\_\_\_ is voltage independent.
  - a) semiconductor

b) metal

c) insulator

- d) space charge
- 9) The light modulation band width is given by

a) Af = 
$$\frac{\Delta\omega}{2\pi}$$

b) Af = 
$$\Delta \omega$$
.2 $\pi$ 

c) Af = 
$$\frac{2\pi}{\Delta\omega}$$

d) 
$$\Delta\omega^{2\pi}$$

- 10)  $\frac{dv}{dt}$  can be limited by connecting a
  - a) resistance in series with the device
  - b) capacitance in series with the device
  - c) series resistance and capacitance in series with device
  - d) series resistance and capacitance in shunt with device
- 11) In a MIS-diode, strong inversion occurs at

a) 
$$V < V_{T}$$

b) 
$$V_{T} = 0$$

c) 
$$V = V_T$$

d) 
$$V = 0$$



	12)	Dominating operating process for laser diode	is	
		a) stimulated emission	b) transmission	
		c) absorption	d) spontaneous emission	
	13)	in GaAs makes it feasible for ultra hi	gh speed CCD's.	
		a) Low electron mobility	b) High electron mobility	
		c) Low hole mobility	d) High electron concentration	
	14)	Triac is adirectional device.		
		a) uni	b) bi	
		c) tri	d) none of the above	
2.	Att	empt the following (any three):		14
	a)	Modern MOSFET's are fabricated on <100 >	oriented Si, - Comment.	
		Switching characteristic of a transistor		
	c)	Photodiode		
	d)	Burried Channel CCD.		
3.	a)	Discuss the potential well model for the charg	e storage mechanism.	10
	b)	Calculate the modulation band width of a GaA	s LED with a carrier life time of	
		100 ps.		4
4.	a)	With a good sketch of I-V characteristic desc (GTO).	ribe Gate Turn Off thyristor	10
	b)	Write a note on CMOS inverter.		4
5.	a)	Discuss in detail the Thyrister - MOSFET cha	racteristic of a MCT.	10
	b)	Mention its merits and demerits.		4
6.	a)	Based on a single temperature model, obtain for a GaAs.	velocity - field characteristic	10
	b)	Mention the important conclusions drawn from	n this V-F characteristic.	4
7.	Wr	ite notes on ( <b>any two</b> ) :		14
		IGBT		
	,	Triac		
	,	TFT		
	,	Tunnel diode.		
	۵,			



Seat	
No.	

# M.Sc. - II (Sem. - III) Examination, 2015

PHYSICS (Materials Sc Instrumentation		
Day and Date : Wednesday, 18-11-2015 Time : 2.30 p.m. to 5.00 p.m.	٦	Γotal Marks : 70
Instructions: 1) Q. 1 and 2 compulso 2) Answer any three que 3) All questions carry eq 4) Use of non-programm	estions from Q. 3 to Q. 7.	l.
1. Objective questions.		14
a) Choose correct alternatives :		8
i) Which of the following is digital trans	sducer?	
a) Strain Gauge	b) Encoder	
c) LVDT	d) Thermistor	
ii) Strain Gauge, LVDT and thermister	are examples of	
<ul> <li>a) Active transducers</li> </ul>	b) Passive transducers	
c) Analog transducers	d) Digital transducers	
iii) Piezo-electric transducer produces	emf, when it is subjected	to
a) Mechanical force	b) Humidity	
c) Illuminations	d) Heat	
iv) The standard supply voltages for ord	dinary operational amplific	eris
a) $\pm 15V$ b) $\pm 20V$	c) $\pm 9 V$ d) $\pm 10$	V
v) A differential amplifier amplifies		
a) Addition of two signals	b) Difference of two sign	als
c) Multiplication of two signals	d) All of the above	
vi) The gain of the voltage follower is	-) 100 -1) 0	
a) 1 b) 2	c) 100 d) 0	
vii) Function generator is used to generator		
a) Sine wave	b) Square wave	
c) Triangular	d) All of the above	ВТО

### **SLR-MM-407**



	Vii	ii) The output of the DAC can be either a) Voltage or resistance b) Voltage or current c) Voltage or capacitance d) Current or resistance	
	i ii iv	Fill in the blanks:  i) The resistance of LDR when exposed to light energy.  ii) The humidity is expressed in  ii) is used to recover the signal buried in noise.  v) Spikes can be obtained by differentiating wave.  v) The resolution of the ADC is given by  vi) Multiplexer is used to	6
2.	a) \ b) <b>l</b>	empt the following : Write a note on optical transducers. Explain principle of phase sensitive detector. Discuss the working of Q-meter.	14
3.	,	Discuss the principle and working of various digital transducers.	10
4.	·	Explain voltage to frequency converter.  With neat diagram discuss the principle and working of flow transducers.	4 10
	,	Write applications of logarithmic amplifiers.	4
5.	,	With a neat schematic explain the working of lock-in amplifier.  Describe the operation of isolation amplifier.	10 4
6.	a) \	With neat block diagram explain the working of dual trace oscilloscope.	10
	b) \	Write a note on wave analyzer.	4
7.	a) I	Describe the working of dual slope type ADC with diagrams.	10
	b) I	Explain principle of frequency meter.	4

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Seat	
No.	

## M.Sc. (Part – II) (Semester – III) Examination, 2015 PHYSICS (Materials Science) (New – CGPA) Paper No. – XI: Elements of Material Science

Max. Marks: 70 Day and Date : Friday, 20-11-2015 Time: 2.30 p.m. to 5.00 p.m. *Instructions*: 1) Q (1) and (2) are compulsory. 2) Answer any three questions from Q. 3 to Q. 7. 3) All questions carry equal marks. 4) **Use** of non programmable calculator is **allowed**. 1. Objective Questions. 14 a) Select the correct alternative: 8 1) Photoconductive effect means a) The decreased conductivity of an illuminated semiconductor junction b) The increased conductivity of an illuminated semiconductor junction c) The conversion of photonic energy to electromagnetic energy d) The conversion of an electromagnetic energy to photonic energy 2) What semiconductor material is used in the construction of LED? a) Silicon b) Germanium c) Gallium d) Gallium arsenide 3) \_\_\_\_\_ is not a characteristic property of ceramic material. a) High temperature stability b) High mechanical strength c) Low elongation d) Low hardness 4) Thermal conductivity in polymers increases with a) Increase in crystallinity b) Decrease in crystallinity c) Both a) and b) d) None 5) Argon laser causes reaction in a) Black objects b) Yellow objects c) Brown objects d) Red objects

**SLR-MM – 408** 6) Poole-Frenkel effect is present in a) Metal b) Insulator c) Conductor d) All of the above 7) Which one of these statements is true? a) Gold at the nanoscale is red b) Copper at the nanoscale is green c) Silicon at the nanoscale is insulator d) Gold at the nanoscale is yellow 8) Electro-luminescence occurs in b) Electrical insulators a) Electrical conductors c) p-n junctions d) All b) Fill in the blanks: 6 1) The phenomenon where emission of light stops as soon as the incident light is cut off is known is 2) The tetrahydral bond angle of (sp3) bond is \_\_\_\_\_\_ 3) In the absorption process the photon is 4) The energy corresponding to the wavelength 1240 nm is \_\_\_\_\_ 5) The shifting of absorption towards lower energy is known as \_\_\_\_\_ shift. 6) \_\_\_\_\_ is the most commonly used color of an LED. 2. Write short notes: 14 1) Nucleation and growth mechanism in nanomaterials. 5 2) Polymer materials. 5 3) Explain the absorption in insulators and semiconductors. 4 3. a) Explain the basic principle of luminescence, give its classification and explain each class with applications in brief. 8 b) Interaction of light with matter. 6 4. a) Explain the synthesis techniques and characterization of nanomaterials. 8 b) Explain few applications of the nanomaterials. 6 5. a) Give difference between crystalline and non-crystalline solids. Explain the different chemical bonds in the solids with suitable examples. 8 b) Give the classification of ceramics, explain its structure and properties. 6

\_\_\_\_\_

8

6

8

6

6. a) What are nanomaterials? Explain different properties of nanomaterials.

b) Explain the polymerization mechanism and degree of polymerization.

7. a) Explain in details different types of excitons present in semiconductors.

b) Explain photodetector bias circuits and performance of photodetectors.

Seat No.

# M.Sc. (Part – II) (Semester – III) Examination, 2015 PHYSICS (Materials Science) (Paper – XII) Dielectrics and Ferroelectric Materials (New) (CGPA)

Day and Date: Monday, 23-11-2015 Total Marks: 70

Time: 2.30 p.m. to 5.00 p.m.

Instructions: 1) Q. 1 and Q. 2 are compulsory.

- 2) Answer any three questions from Q. 3 to Q. 7.
- 3) All questions carry equal marks.
- 1. Objective questions:

14

a) Choose correct alternatives:

8

1) The expression for the electric field strength for spherical distribution of charge is

a) 
$$E = \frac{1}{4\pi\epsilon_0} \frac{Q}{r^3} \vec{r}$$

b) 
$$E = \frac{1}{4\pi\epsilon_0} \frac{Q}{r^2} \vec{r}$$

c) 
$$E = \frac{1}{4\pi r^3 \epsilon_0}$$

d) 
$$E = \frac{1}{4\pi\epsilon_0}$$

2) The Clausius-Mossotti relation for the dielectrics is

a) 
$$\frac{\varepsilon_r - 1}{\varepsilon_r + 2} = \frac{n\alpha}{3\varepsilon_0}$$

b) 
$$\frac{\varepsilon_r - 1}{\varepsilon_r + 2} = \frac{n\alpha}{\varepsilon_0}$$

c) 
$$\frac{\varepsilon_r + 1}{\varepsilon_r + 2} = \frac{n\alpha}{3\varepsilon_0}$$

d) 
$$\frac{\varepsilon_r - 1}{\varepsilon_r - 2} = \frac{n\alpha}{3\varepsilon_0}$$

3) The relation between magnetic field (H), magnetic induction (B) and magnetization (M) is given by

a) 
$$B = \mu_0 (H + M)$$

b) B = 
$$\mu_0$$
 (H – M)

c) 
$$B = \mu_0 (H \times M)$$

d) 
$$B = \mu_0 (H / M)$$



- 4) According the Maxwell's equation, the isolated poles do not exists is defined by
  - a)  $\nabla \cdot \mathbf{B} = \mathbf{0}$
  - b)  $\nabla \cdot \mathbf{E} = \mathbf{0}$
  - c)  $\nabla \times \mathbf{E} = -\frac{\partial \mathbf{B}}{\partial t}$
  - d)  $\nabla \times B = J + \frac{\partial D}{\partial t}$
- 5) Dielectric constant of air is
  - a) 0
- b) ∞
- c) 1
- d) 1.8
- 6) Ferrites are \_\_\_\_\_ materials.
  - a) Paramagnetic
- b) Diamagnetic
- c) Ferromagnetic
- d) None of these
- 7) The band gap of Germanium materials is \_\_\_\_\_
  - a) 0.4 eV

b) 0.3 eV

c) 0.7 eV

- d) 1.1 eV
- 8) Succeptibility  $(\chi)$  of diamagnetic material is
  - a) 0
- b) +1
- c) -1
- d) ∞

#### b) True or False:

6

- i) Magnetic materials provide path to magnetic flux.
- ii) Aluminium oxide is an example for diamagnetic material.
- iii) Rochelle salt does not exhibits ferro electric property.
- iv) Below the Curie temperature all ferromagnetic materials exhibit hysteresis.
- v) In piezo electric crystals, when an electric field is applied its mechanical dimension is altered.
- vi) The resistivity of the Ferrites is very much less than that of the ferromagnetic materials.



2.	Att	tempt the following:	14
	i)	Express Maxwell's equations in integral and differential forms.	4
	ii)	Derive the Clausius-Mosotti equation and interpret it's significance.	5
	iii)	Write a note on Quarter wave plate.	5
3.	a)	What is meant by polarization mechanism in Dielectrics? Discuss various Polarization mechanisms in dielectrics and explain the temperature dependence.	8
	b)	Describe the characteristics and significance of Cole-Cole plot?	6
4.	a)	Explain in detail the relation between the dielectric relaxation and chemical structure.	8
	b)	Write a short note on modulation of light.	6
5.	•	What is Electro-optic effect ? Discuss in detail, the linear electro-optic effect. Explain the photorefractive effect.	8
6.	a)	Explain the phenomenological approach to piezoelectric effect. Discuss various piezoelectric parameters and their measurements.	8
	b)	Discuss the Magneto-Optic effect with suitable example.	6
7.		Discuss in detail the characteristics features and properties of BaTiO <sub>3</sub> crystal. Derive an expression for the relation between dielectric constant and dielectric loss factor and interpret the results.	. 8

Seat No.

### M.Sc. – II (Semester – III) (Old-CGPA) Examination, 2015 **PHYSICS (Materials Science)**

### Paper - IX : Semiconductor Devices

Day and Date: Monday, 16-11-2015 Max. Marks: 70

Time: 2.30 p.m. to 5.00 p.m.

**Instructions**: 1) Attempt **five** questions.

- 2) Questions 1 and 2 are compulsory.
- 3) Attempt any 3 from Q. 3 to Q. 7.
- 4) Use of nonprogrammable calculator is allowed.

1	Choose the correct all	ternative
	CHOOSE THE COHECT AN	ıcınanve i

14

1) The over-drive of a BJT is given by \_\_\_\_\_

a) 
$$\frac{I_c}{I_{c(sat)}}$$
 b)  $\frac{I_b}{I_{b(sat)}}$  c)  $\frac{I_{c(sat)}}{I_{c}}$ 

b) 
$$\frac{I_b}{I_{b(sat)}}$$

c) 
$$\frac{I_{c(sat)}}{I_{c}}$$

d) 
$$\frac{I_{b \text{ (sat)}}}{I_{b}}$$

2) Power MOSFET's are \_\_\_\_\_ controlled devices

a) Power

b) Current

c) Voltage

d) Both b) and c)

3) Burried channel CCD has a transfer inefficiency as \_\_\_\_\_

a) 
$$10^{-1}$$
 to  $10^{-2}$ 

b) 
$$10^{-2}$$
 to  $10^{-3}$ 

c) 
$$10^{-3}$$
 to  $10^{-4}$ 

d) 
$$10^{-4}$$
 to  $10^{-5}$ 

4) Enhancement MOSFET's respond only to \_\_\_\_\_

a) Negative V<sub>GS</sub>

b) Positive 
$$V_{GS}$$

c) Both a) and b)

d) No voltage required



In a MIS diode, the	e ON-set of strong inv	vers	ion occurs at		
a) $\psi_S = 2\psi_B$	b) $\Psi_S = \Psi_B$	c)	$\psi_S = 0$	d)	$\psi_S = \infty$
Transferred electro	on devices operates a	at_			
a) H <sub>z</sub>	b) KH <sub>z</sub>	c)	$MH_z$	d)	$GH_z$
Wavelength and p	hoton energy are rela	ted	as		
a) $\lambda = \frac{1.24}{hv}$	b) $\frac{12.4}{hv}$	c)	<u>hυ</u> 1.24	d)	<u>hυ</u> 12.4
It is possible to tra	nsfer last bit of signal	l in a	CCD because	of th	ne presence of
a) Thermal diffusi	on	b)	Self induced dri	ift	
c) Fringing field		d)	Interface		
Dominating operat	ting mechanism for L	ASE	:R is		_
a) Stimulated emi	ission	b)	Absorption		
c) Transmission		d)	Spontaneous er	mis	sion
,	lled NDR devices,	-	•		
,			•	ned	I.
In a current contro	ament	b)	are forr	ned mer	I.
In a current contro  a) High current fila  c) High field doma	ament	b) d)	are forr Low current fila Low field domai	med med	I. nt
In a current contro  a) High current fila  c) High field doma	ament ains	b) d) y	are forr Low current fila Low field domai anne	med mer ns alin	I. nt
In a current contro  a) High current fila  c) High field doma  Interface traps are  a) O <sub>2</sub>	ament ains e normally reduced by	b) d) y	are forn Low current filat Low field domai anne H <sub>2</sub>	med mer ns alin	l. nt g.
In a current contro  a) High current fila  c) High field doma  Interface traps are  a) O <sub>2</sub> Tunnel diode exhib	ament ains e normally reduced by b) N <sub>2</sub>	b) d) y c) rolle	are forn Low current filat Low field domai anne H <sub>2</sub>	med mer ns alin d)	l. nt g.
In a current contro  a) High current fila  c) High field doma  Interface traps are  a) O <sub>2</sub> Tunnel diode exhib  a) Current	ament ains e normally reduced by b) N <sub>2</sub> pitsconti	b) d) y c) rolle c)	are forn Low current filat Low field domai anne H <sub>2</sub> d NDR. Power	med med ins alin d)	I. nt g. Cl <sub>2</sub> None
In a current contro  a) High current fila  c) High field doma  Interface traps are  a) O <sub>2</sub> Tunnel diode exhib  a) Current  In a Si – SiO <sub>2</sub> MOS	ament ains e normally reduced by b) N <sub>2</sub> bitsconti b) Voltage S diode, the layer SiO	b) d) y_ c) rolle c) x is	are forn Low current filat Low field domai anne H <sub>2</sub> d NDR. Power	med mer ns alin d) d)	I. nt g. Cl <sub>2</sub> None n
In a current contro a) High current fila c) High field doma Interface traps are a) $O_2$ Tunnel diode exhiba a) Current In a Si – SiO <sub>2</sub> MOS a) $x = 0$	ament ains e normally reduced by b) N <sub>2</sub> bitsconti b) Voltage S diode, the layer SiO	b) d) y c) rolle c) x is c)	are form Low current filat Low field domai anne H <sub>2</sub> d NDR. Power stoichiometric w x = 2	med mer ns alin d) d)	I. nt g. Cl <sub>2</sub> None n
In a current contro a) High current fila c) High field doma Interface traps are a) $O_2$ Tunnel diode exhiba a) Current In a Si – SiO <sub>2</sub> MOS a) $x = 0$	ament ains e normally reduced by b) N <sub>2</sub> bitsconti b) Voltage S diode, the layer SiC b) x = 1	b) d) y c) rolle c) x is c)	are form Low current filat Low field domai anne H <sub>2</sub> d NDR. Power stoichiometric w x = 2	med mer ns alin d) d)	I. nt g. Cl <sub>2</sub> None n
	a) $\psi_S = 2\psi_B$ Transferred electrons a) $H_Z$ Wavelength and points a) $\lambda = \frac{1.24}{hv}$ It is possible to trans a) Thermal diffusions c) Fringing field  Dominating operations	a) $\psi_S = 2\psi_B$ b) $\psi_S = \psi_B$ Transferred electron devices operates a a) $H_Z$ b) $KH_Z$ Wavelength and photon energy are related a) $\lambda = \frac{1.24}{h\nu}$ b) $\frac{12.4}{h\nu}$ It is possible to transfer last bit of signal a) Thermal diffusion c) Fringing field	a) $\psi_S = 2\psi_B$ b) $\psi_S = \psi_B$ c) Transferred electron devices operates at a) $H_Z$ b) $KH_Z$ c) Wavelength and photon energy are related a) $\lambda = \frac{1.24}{h\nu}$ b) $\frac{12.4}{h\nu}$ c) It is possible to transfer last bit of signal in a a) Thermal diffusion b) c) Fringing field d) Dominating operating mechanism for LASE	a) $\psi_S = 2\psi_B$ b) $\psi_S = \psi_B$ c) $\psi_S = 0$ Transferred electron devices operates at a) $H_Z$ b) $KH_Z$ c) $MH_Z$ Wavelength and photon energy are related as a) $\lambda = \frac{1.24}{hv}$ b) $\frac{12.4}{hv}$ c) $\frac{hv}{1.24}$ It is possible to transfer last bit of signal in a CCD because a) Thermal diffusion b) Self induced drift c) Fringing field d) Interface  Dominating operating mechanism for LASER is	a) $H_z$ b) $KH_z$ c) $MH_z$ d) Wavelength and photon energy are related as



2.	Att	tempt (any three):	14
	a)	Role of fringing field in charge transfer mechanism.	5
	b)	Write a note on IR-LED.	4
	c)	Triac.	5
	d)	Measurement of interface trap density.	4
3.	a)	Discuss the potential well model for the charge storage mechanism in a CCD.	10
	b)	Write a note on TFT.	4
4.	a)	Discuss and compare transferred electron effect in GaAs and InP.	10
	b)	What is stretch out ? Why is it ?	4
5.	a)	What are dV/dt and $\frac{dI}{dt}$ effects ?	10
	b)	Write a note on frequency response of a CCD.	4
6.	a)	Explain how transfer efficiency can be improved with a Burried Channel CCD.	10
	b)	Write a note on diac.	4
7.	a)	Based on a single temperature model, obtain velocity-field characteristic for GaAs.	10
	b)	Draw the important conclusions of V – F characteristics.	4



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## M.Sc. – II (Semester – III) (C.G.P.A.) Examination, 2015 PHYSICS (Materials Science) (Paper – X) (Old) Instrumentation

	(	Instrume	ntation	ι, (σ.α)	
•	Date: Wednesday, 0 p.m. to 5.00 p.m.			Total Marks : 70	
Instru			stions from Q. <b>3</b> to	Q. <b>7</b> .	
1. Objec	ctive questions :			14	
a) Ch	noose correct alterr	natives :		8	
, i)	Displacement can	be measured usi	ng		
•	a) Thermistor		_	d) Microphone	
ii)	Which of the follow	ving is a voltage (	generating type tra	ansducer?	
	a) microphone	b) tube light	c) solar cell	d) thermistor	
iii)	A pH value of 7, ir	ndicates the solut	ion is		
	a) acidic	b) alkaline	c) neutral	d) none of the above	
iv)	An instrumentatio	n amplifier consis			
	a) thermistor		b) lock-in amplif		
	c) op-amps		d) all of the above		
v)	In lock-in amplifier locks into frequen		comes from the fac	ct that the instrument	
	<ul><li>a) Input signal</li></ul>		b) IF signal		
	c) Reference sign	nal	d) Output signal		
vi)	The sample and h	old circuit uses th	ne following device	e as a switch	
	a) relay		b) on-off switch		
	c) FET		d) BJT		
vii) The instrument which presents graphically the energy distributio signal as a function of frequency is					
	a) oscilloscope		b) frequency meter		
	c) spectrum analy	yser	d) X – Y recorde	er	
viii)	A piezo-electric cr	ystal can be use	d as a transducer	to measure	
	a) sound	b) light	c) pressure	d) speed	
				P.T.O.	

### **SLR-MM - 411**



	b)	Fill in the blanks :	6			
		i) Loudspeaker converts energy into energy.				
		ii) An instrumentation amplifier is constructed using amplifiers.				
iii) Thermistor is a temperature coefficient device.						
		iv) Thickness can be measured with				
		v) Spectrum analyser is used to measure				
		vi) Hydrogen ion concentration of a solution can be measured using				
2.	Att	empt any three:	14			
	a)	Discuss the working of thermo electric transducers.				
	b)	Explain the feedback transducer system.				
	c)	Explain the working of Q-meter.				
	d)	How does a S/H circuit work ? Explain.				
3.	a)	Discuss the classification of transducers in detail with examples.	10			
	b)	What is Hall effect ? Explain.	4			
4.	a)	) Explain in detail, the working of a temperature balance system.				
	b)	Mention the basic characteristics of an instrumentation amplifier.	4			
5.	a)	With neat block diagram, explain the operation of a digital frequency meter.	10			
	b)	Write a note on current to voltage converter.	4			
6.	a)	Draw the block diagram of a lock-in amplifier and explain the operation in				
		detail.	10			
	b)	Write a note on frequency to voltage converter.	4			
7.	a)	Discuss in detail, the working of a standard interface system.	10			
	b)	Write a note on energy meter.	4			

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Seat No.

## M.Sc. (Part – II) (Semester – IV) (CGPA) Examination, 2015 PHYSICS (Material Science) (Paper – XIII) Computational Methods and Programming

Day and Date: Tuesday, 17-11-2015 Total Marks: 70

Time: 2.30 p.m. to 5.00 p.m.

Instructions: 1) Q. No. 1 and Q. No. 2 are compulsory.

- 2) Answer any three questions from Q. No. 3 to Q. No. 7.
- 3) **Use** of Non programmable calculator is **allowed**.
- 4) All questions carry equal marks.
- 1. a) Choose the correct alternative:
  - i) For solving set of equation AX = B, in which the matrix A is transformed to diagonal matrix
    - A) Gauss Seidal method
    - B) Gauss elimination method
    - C) Gauss Jordan method
    - D) Gauss Jacobi's method
  - ii) In solving a set of simultaneous ordinary differential equations by  $4^{th}$  order Runge kutta method, if y(0) = 1, h = 0.1,  $k_1 = 0.1$ ,  $k_2 = 0.1150$ ,  $k_3 = 0.1171$  and  $k_4 = 0.1359$  then value of y(0.1) = ?
    - A) 0.11668

B) 1.16186

C) 1.11668

- D) 0.16186
- iii) Using the principle of least square, first normal equation of the curve  $y = ae^{bx}$  will be

A) 
$$\sum \log y = n \sum \log a + b \sum \log x$$

B) 
$$\sum y = n \sum a + b \log x$$

C) 
$$\sum \log y = n \sum a + b \sum \log x$$

D) 
$$\sum \log y = n \sum \log a + b \sum x$$

6



- iv) Gauss Seidal method converges only, if the coefficient matrix is
  - A) Singular matrix

- B) Non singular matrix
- C) Upper triangular matrix
- D) Diagonally dominant
- v) The positive real root of the equation f(x) = 0 lies between a and b if.
  - A) f(a) f(b) > 0

B) f(a) f(b) = 0

C) f(a) f(b) < 0

- D) f(a) f(b) > 1
- vi) Milne method is used
  - A) To find out the root of algebraic equation
  - B) To solve ordinary D.E.
  - C) To evaluate integration
  - D) None of these
- b) State **true** or **false**:

8

- i) The Principle of least square is based on minimizing the  $\sum E_i^2$ , where  $Ei = (y_i y)^2$ .
- ii) The positive real root of the equation  $x^3 + 3x 1 = 0$  lies between 0 and 1.
- iii) To predict Adam's Method at least 4 values of y, prior to the desired values are required.
- iv) In Newton's Cotes formula if f(x) is interpolated at equally spaced nodes by a polynomial of degree three then it represents three eight rule.
- v) To fit the straight line y = a + xb to N observations, the normal equations are  $\sum y = a \sum x + bN$ ;  $\sum xy = a \sum x^2 + b \sum x$ .
- vi) The value of  $I = \int_{0}^{0.5} X^2 dx$  by Simpson's  $1/3^{rd}$  rule is 1.00073.
- vii) Gauss Jordan method for solving the system AX = B fails if matrix A is not diagonally dominant.
- viii) Gauss Elimination is an non-iterative method.



#### 2. Write short notes on:

- a) Write a note on Quadratures and explain how to arrive at Simpson's one third rule.
- 5

b) What are random numbers? Explain its use.

**4** 5

8

6

8

- c) Write a note on need of numerical solution of the differential equations.
- 3. a) Write a note on Newton Raphson Method. Find a positive root of  $x^2 + 4 \sin x = 0$  by False Position Method.
  - b) Using improved Euler Method find y at x = 0.1 and y at x = 0.2, given

$$\frac{dy}{dx} = y - \frac{2x}{y} \text{ with } y(0) = 1.$$

- 4. a) Evaluate the integral  $I = \int_{0}^{2} e^{x^{2}} dx$  by taking h = 0.2 and n = 10 using Simpson's three eight rule.
  - b) Find the value of y(1.85) and y(2.4) using for the following data:

X	1.7	1.8	1.9	2.0	2.1	2.2	2.3
у	5.474	6.050	6.686	7.389	8.166	9.025	9.974

5. a) The curve  $y = ab^x$  is fitted to the data:

<b>x</b> :	2	3	4	5	6	8
<b>y</b> :	8.3	15.4	33.1	65.2	126.4	146

Find the best values of a and b.



b) Solve the system of equation by Gauss Jordan method.

6

$$x + 2y - 12z + 8w = 27$$

$$5x + 4y + 7z - 2w = 4$$

$$6x - 12y - 8z + 3w = 49$$

$$3x - 7y - 9z - 5w = -11$$

6. a) Perform four iterations of false position method to find the positive root of the equation  $x \log_{10} x - 1.2 = 0$ .

8

b) Solve the following system of equation by Gauss Seidal method.

6

$$10x + y + 2z = 44$$

$$2x + 10y + z = 51$$

$$x + 2y + 10z = 61$$

8

7. a) Evaluate  $\int_{0}^{0.5} \frac{x dx}{\sin x}$ , using Romberg's Integration. b) Given  $\frac{dy}{dx} = \frac{1}{2}(1+x^2)y^2$  and y(0) = 1, y(0.1) = 1.06, y(0.2) = 1.12,

6

y(0.3) = 1.21, find y(0.4) by Milne's Predictor Corrector Method.

**SLR-MM – 416** 



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No.	

### M.Sc. (Part – II) (Semester – IV) (CGPA) Examination, 2015 PHYSICS (Materials Science) Paper No. – XI: Magnetic Materials

Day and Date: Saturday, 21-11-2015 Total Marks: 70

Time: 2.30 p.m. to 5.00 p.m.

Instructions: 1) Q.(1) and (2) are compulsory.

- 2) Answer any three questions from Q. 3 to Q. 7.
- 3) All questions carry equal marks.

1. Objective questions:

(14)

8

- a) Choose correct alternatives:
  - 1) Hall effect can be used to measure
    - a) mobility of semiconductors
- b) conductivity of semiconductors
- c) resistivity of semiconductors
- d) all of these
- 2) Example for dia-magnetic materials
  - a) super conductors

b) alkali metals

c) transition metals

- d) ferrites
- 3) In a ferroelectric material, the spontaneous polarization vanishes above
  - a) transition temperature
- b) debye temperature
- c) fermi temperature
- d) curie temperature
- 4) The magnetic domains in a non-magnetized piece of iron are characterized by which orientation?
  - a) parallel to the magnetic axis
  - b) anti-parallel (opposite direction) to the magnetic axis
  - c) random
  - d) perpendicular to the magnetic axis

above which they are paramagnetic is called

a) Curie temperature

c) transition temperature

5) The temperature below which certain materials are antiferromagnetic and

b) Neel temperature

d) Weiss temperature



		6)	6) The susceptibility of ferromagnetic materials varies with temperature as					
			a) $\chi = C/(T \pm \theta)$	b)	$\chi = C/(T + \theta)$			
			c) $\chi = C/(T-\theta)$	d)	$\chi = C/T$			
		7)	The property of ferromagnetic mate shape or dimensions during the pro-		•			
			a) magnetoresistance	b)	electrostriction			
			c) magnetostriction	d)	none of these			
		8)	The property of a material to change when an external magnetic field is a					
			a) magnetoresistance	b)	electrostriction			
			c) magnetostriction	d)	anomalous hall effect			
	b)	Fil	l in gaps <b>True</b> or <b>False</b> :			6		
		1)	Susceptibility of diamagnetic materia	als	does not depend on temperature.			
		2)	Susceptibility of antiferromagnetic n	nat	erials is large and negative.			
		3)	The paramagnetic substance possess angular momentum.	ses	permanent dipoles due to vanishing			
		4)	The phenomenon of magnetic mom or ions occurs in materials known as					
		5)	Cubic ferrites have the inverse spir symmetry.	al (	crystal structure, which is cubic in			
		6)	A magnetic domain is a region within magnetization.	a m	agnetic material which has uniform			
2.	Wı	rite	short answers :			(14)		
a) Distinguish between ferromagnetic and antiferromagnetic orders.								
	b) What is magnetostatic energy?							
	c)	Er	nlist the applications of magnetostric	tior	l.	4		